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November 2013



FGPF4533 330 V PDP Trench IGBT

Features

- High Current Capability
- Low Saturation Voltage: V_{CE (sat)} = 1.55 V @ IC = 50 A
- High Input Impedance
- Fast Switching
- RoHS Compliant

Applications

• PDP TV, Consumer Appliances, Lighting

General Description

Using novel trench IGBT technology, Fairchild's new series of trench IGBTs offer the optimum performance for consumer appliances, PDP TV and lighting applications where low conduction and switching losses are essential.



Absolute Maximum Ratings

Symbol	Description	Ratings	Unit	
V _{CES}	Collector to Emitter Voltage		330	V
V _{GES}	Gate to Emitter Voltage		± 30	V
I _{C pulse(1)*}	Collector Current	@ T _C = 25 ^o C	200	A
P _D	Maximum Power Dissipation	@ T _C = 25°C	28.4	W
	Maximum Power Dissipation	@ T _C = 100 ^o C	11.4	W
TJ	Operating Junction Temperature	-55 to +150	°C	
T _{stg}	Storage Temperature Range	-55 to +150	°C	
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	°C	

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	4.4	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	-	62.5	°C/W

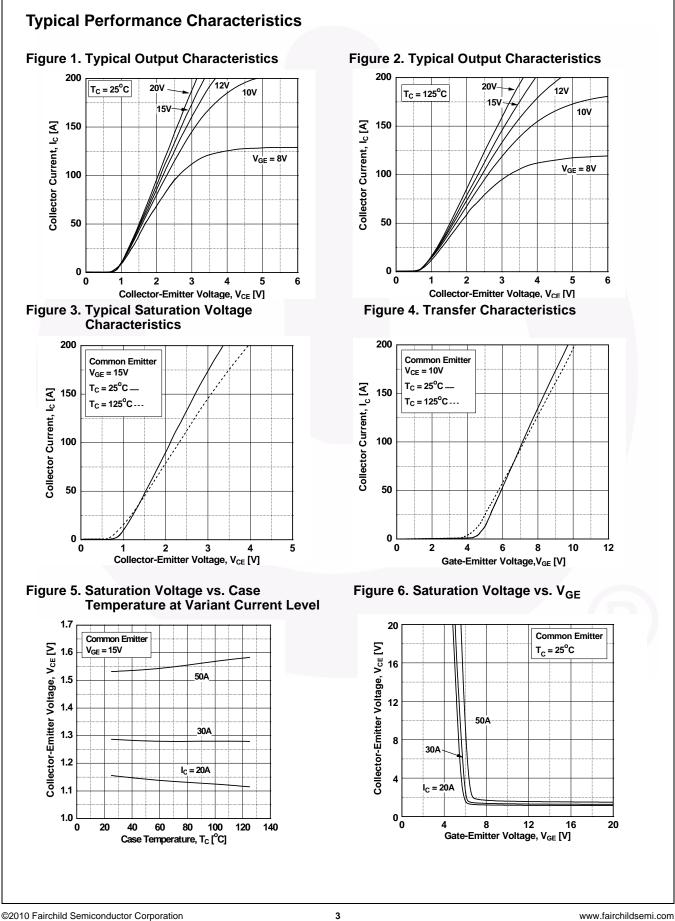
Notes:

(1) Half Sine Wave, D < 0.01, pluse width < 5 μ sec

* Ic_pluse limited by max Tj

Part Nun	nber 1	Top MarkFGPF4533	PackageTO-220F	Packing Method Tube	Reel Size	e Ta	ape Width	Qu	Quantity	
FGPF45	33				N/A		N/A		50	
Electric	al Chai	racteristi	cs of the l	GBT $T_{C} = 25^{\circ}C$ unless oth	erwise noted					
Symbol	Parameter		Test Conditions		Min.	Тур.	Max.	Unit		
Off Charac	teristics									
BV _{CES}	Collector to Emitter Breakdown Voltage		$V_{GE} = 0 V, I_{C} = 250 \mu A$		330	-	-	V		
∆BV _{CES} ∆T _J	Temperat Voltage	Temperature Coefficient of Breakdown /oltage		$V_{GE} = 0 \text{ V}, \text{ I}_{C} = 250 \mu\text{A}$		-	0.3	-	V/ºC	
I _{CES}	Collector	collector Cut-Off Current		V _{CE} = V _{CES} , V _{GE} = 0 V		-	-	100	μA	
I _{GES}	G-E Leak	age Current		$V_{GE} = V_{GES}, V_{CE} = 0$ V	/	-	-	±400	nA	
On Charac	teristics									
V _{GE(th)}	G-E Thre	shold Voltage		$I_{C} = 250 \ \mu A, \ V_{CE} = V_{G}$	E	2.4	3.3	4.0	V	
- (* /		Collector to Emitter Saturation Voltage		I _C = 20 A, V _{GE} = 15 V		-	1.15	-	V	
				$I_{C} = 50 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 25^{\circ}\text{C}$		-	1.55	1.8	V	
	Saturation			$I_{C} = 50$ A, $V_{GE} = 15$ V, $T_{C} = 125^{o}C$		-	1.6	-	V	
Dynamic C	haracteris	tics			i i					
C _{ies}	Input Capacitance Output Capacitance		V _{CE} = 30 V, V _{GE} = 0 V, f = 1 MHz		-	1294	-	pF		
C _{oes}					-	57	-	pF		
C _{res}	Reverse Transfer Capacitance				-	41	-	pF		
Switching	Characteri	istics			i -					
t _{d(on)}	Turn-On I	Delay Time				-	6	-	ns	
t _r	Rise Time	Э		$V_{CC} = 200 \text{ V}, \text{ I}_{C} = 20 \text{ A}$ $R_{G} = 5 \Omega, V_{GE} = 15 \text{ V}$		-	22	- \	ns	
t _{d(off)}	Turn-Off [Delay Time		ResistiveLoad, $T_C = 25^{\circ}$	°C	-	40	-	ns	
t _f	Fall Time					-	220	-	ns	
t _{d(on)}	Turn-On I	Delay Time				-	6	-	ns	
r	Rise Time	e		$V_{CC} = 200 \text{ V}, \text{ I}_{C} = 20 \text{ A}$ $R_{G} = 5 \Omega, \text{ V}_{GE} = 15 \text{ V},$,	-	24	-	ns	
t _{d(off)}	Turn-Off	Delay Time		Resistive Load, $T_C = 1$	25°C	-	42	-	ns	
t _f	Fall Time					-	277	-	ns	
Q _g	Total Gate	e Charge		V _{CE} = 200 V, I _C = 20 A		-	44	-	nC	
Q _{ge}	Gate to E	mitter Charge		V _{CE} = 200 V, IC = 20 A V _{GE} = 15 V		-	6	-	nC	
Q _{gc}	Gate to C	ollector Charg	e			-	14	-	nC	

FGPF4533 — 330 V PDP Trench IGBT



FGPF4533 Rev. C1

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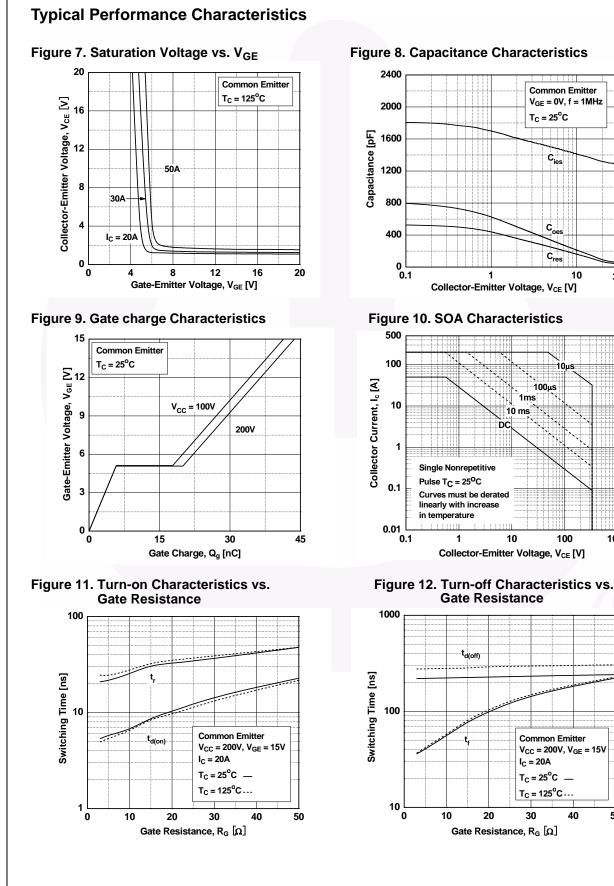


Figure 8. Capacitance Characteristics

C_{ies}

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Cres

0,

100

40

10

30

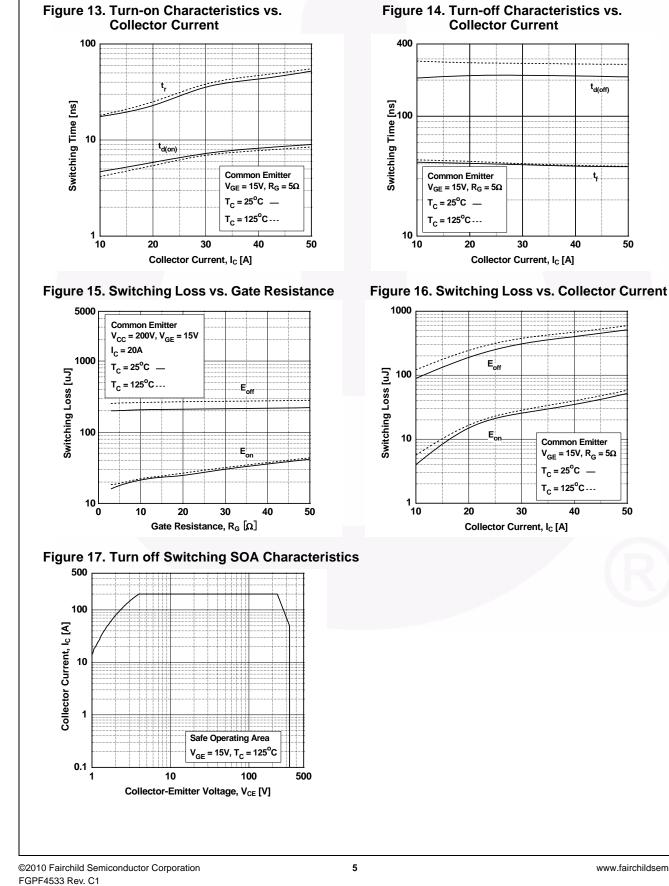
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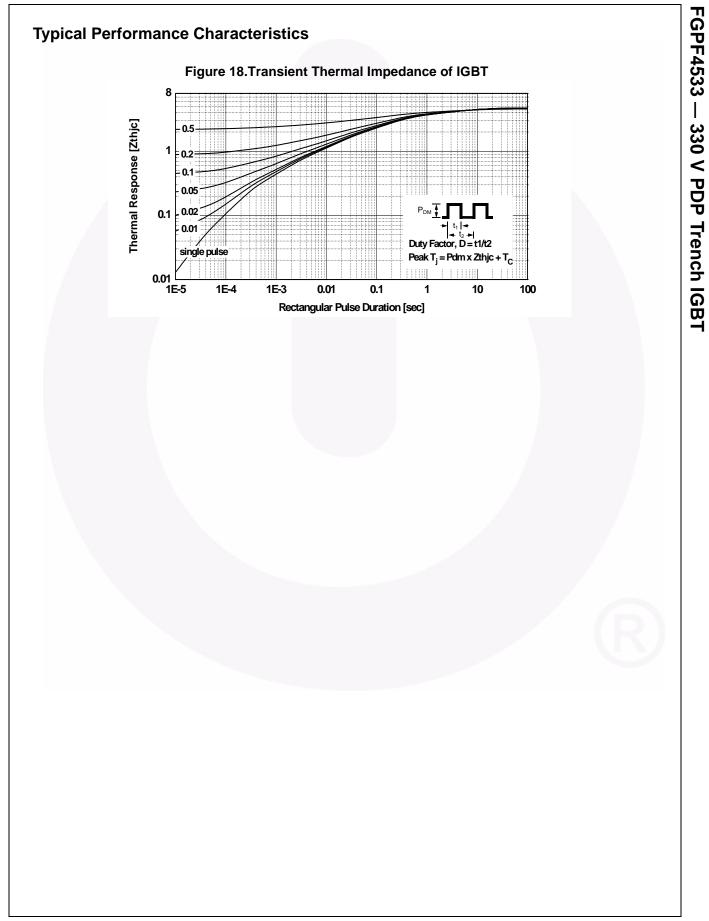
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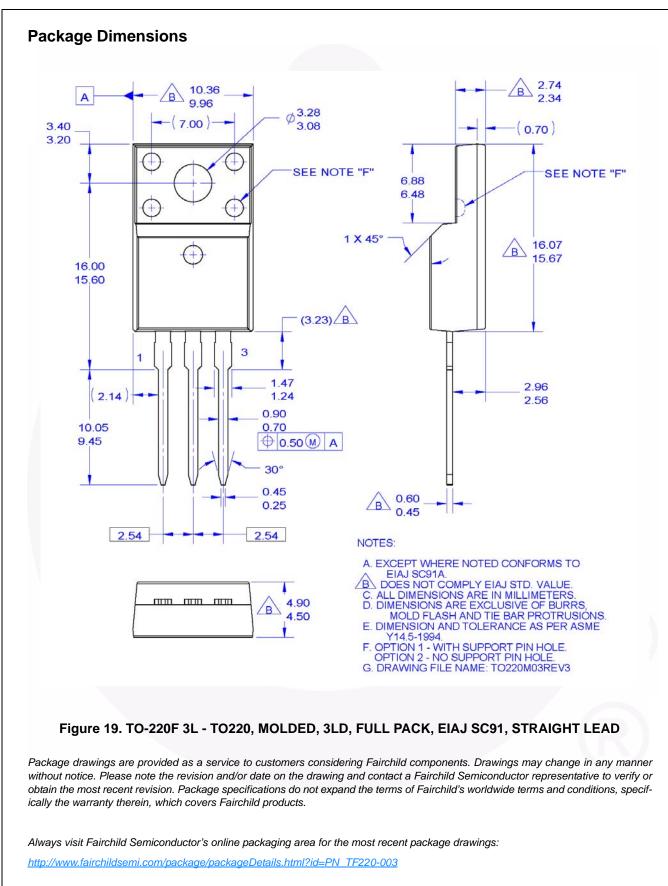
FGPF4533 — 330 V PDP Trench IGBT



Typical Performance Characteristics

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